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Correction: Heterogeneous integration of 8-inch LiNbO₃ films for second harmonic generation

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Correction for 'Heterogeneous integration of 8-inch LiNbO₃ films for second harmonic generation' by Yong Wang et al., *J. Mater. Chem. C*, 2025, <https://doi.org/10.1039/d5tc01952d>.

The authors regret that Fig. 4 was inadvertently replaced with a copy of Fig. 5. The correct version of Fig. 4 is shown in this notice.

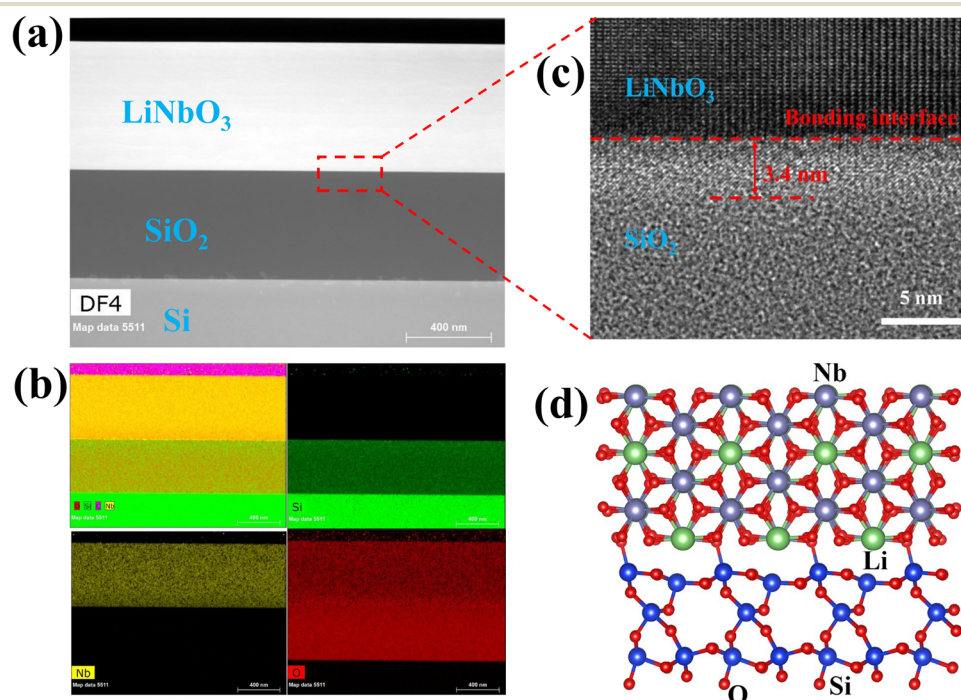


Fig. 4 Cross-section of 8-inch heterogeneous integrated LN wafers: (a) TEM result; (b) EDS mapping results; (c) HRTEM result; (d) atomic structure diagram.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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